| | Hits | Search Text | DBs |
|---|---|---|---|
| 16 | 4 | (IC or (integrat$4 near9 circuit$4)) and non$4volatile and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB |
| 17 | 0 | (IC or (integrat$4 near9 circuit$4)) and $4volatile and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal same (photoresist or resist) same (etch$4 or RIE)) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB |
| 18 | 2 | (IC or (integrat$4 near9 circuit$4)) and (memory near16 cell) and (word near12 line) and (((conduct$3 or word) near16 (line or pattern or layer)) same pedestal same (photoresist or resist) same (etch$4 or RIE)) | US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB |